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A. CLASS IPC 7	HIFICATION OF SUBJECT MATTER H01L21/18 H01L21/266			
According t	to International Patent Classification (IPC) or to both national cla	ssification and IDC		
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Minimum de IPC 7	ocumentation searched (classification system followed by class H01L	ification symbols)		
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EPO-In	ternal, WPI Data, PAJ, INSPEC, CO	MPENDEX		
C. DOCUM	ENTS CONSIDERED TO BE RELEVANT			
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"A" documer	egories of cited documents : nt defining the general state of the art which is not	"T" later document published after or priority date and not in cor	afflict with the application but	
'E' earlier de filling da		clied to understand the princi invention "X" document of particular relevan cannot be considered novel of	nce; the claimed invention or cannot be considered to	
which is citation	nt which may throw doubts on priority claim(s) or s cited to establish the publication date of another or other special reason (as specified) nt referring to an oral disclosure, use, exhibition or leans	involve an inventive step whe "Y" document of particular relevan cannot be considered to invo document is combined with o	en the document is taken alone nce; the claimed invention live an inventive step when the nne or more other such docu-	
'P' documen	nt published prior to the International filing date but an the priority date claimed	ments, such combination being obvious to a person skilled in the art. *&* document member of the same patent family		
	ctual completion of the international search	Date of mailing of the internati	onal search report	
	March 2005 alling address of the ISA	11/03/2005 Authorized officer	11/03/2005	
Name and mailing address of the ISA European Patent Office, P.B. 5818 Patentiaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo ní, Fax: (+31-70) 340-3016		Meacher, D		

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